

TOSHIBA Photocoupler Photorelay

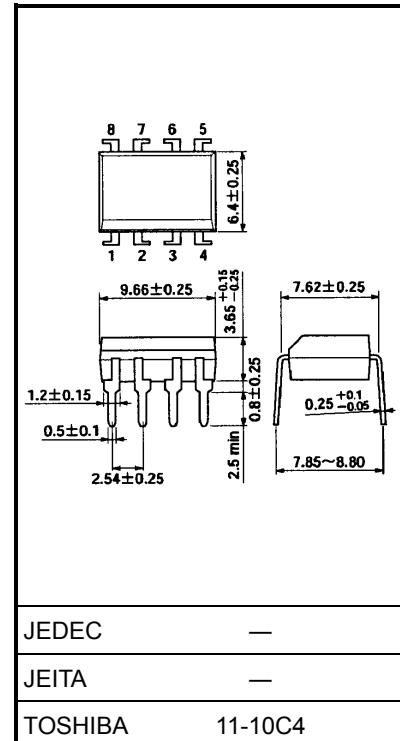
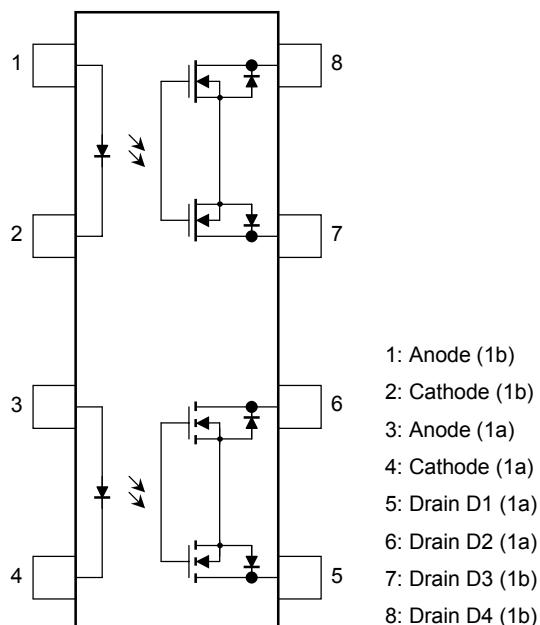
TLP4007G

Telecommunication
 Measurement Equipment
 Security Equipment
 FA

Unit: mm

The Toshiba TLP4007G consists of an aluminum gallium arsenide infrared emitting diode optically coupled to a photo-MOSFET and is the 1-form-A/B photorelay with 350-V withstand voltage.

- Normally closed (1-form-B) device, normally opened (1-form-A) device
- Peak off-state voltage: 350 V (min)
- Trigger LED current: 3 mA (max)
- On-state current: 100 mA (max)
- On-state resistance: 50 Ω (max)
- Isolation voltage: 2500 Vrms (min)

Pin Configuration (top view)

Weight: 0.54 g (typ.)

Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
LED	Forward current	I _F	50	mA	
	Forward current derating (Ta ≥ 25°C)	ΔI _F /°C	-0.5	mA/°C	
	Peak forward current	I _{FP}	1	A	
	Reverse voltage	V _R	5	V	
	Junction temperature	T _j	125	°C	
Detector	Off-state output terminal voltage	V _{OFF}	350	V	
	On-state current	I _{ON}	100	mA	
	Two channel operations (1a1b simultaneous operation)				
	On-state current derating (Ta ≥ 25°C)	ΔI _{ON} /°C	-1.0	mA/°C	
	One channel operation				
Junction temperature		T _j	125	°C	
Storage temperature range		T _{stg}	-55 to 125	°C	
Operating temperature range		T _{opr}	-40 to 85	°C	
Lead soldering temperature (10 s)		T _{sol}	260	°C	
Isolation voltage (AC, 1 min, R.H. ≤ 60%)		(Note 1)	BV _S	2500	Vrms

Note 1: Pins 1, 2, 3 and 4 are shorted together, and pins 5, 6, 7 and 8 are shorted together.

Recommended Operating Conditions

Characteristics	Symbol	Min	Typ.	Max	Unit
Supply voltage	V _{DD}	—	—	280	V
Forward current	I _F	5	10	25	mA
On-state current	I _{ON}	—	—	100	mA
Operating temperature	T _{opr}	-20	—	65	°C

Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition			Min	Typ.	Max	Unit
LED	Forward voltage	V _F	I _F = 10 mA	—	—	1.0	1.15	1.3	V
	Reverse current	I _R	V _R = 5 V	—	—	—	—	10	μA
	Capacitance	C _T	V = 0, f = 1 MHz	—	30	—	—	—	pF
Detector	Off-state current	I _{OFF}	V _{OFF} = 350 V	—	—	—	—	1	μA
	Capacitance (1b)	C _{OFF}	V = 0, f = 1 MHz, I _F = 5 mA	—	30	—	—	—	pF
	Capacitance (1a)		V = 0, f = 1 MHz	—	30	—	—	—	

Coupled Electrical Characteristics ($T_a = 25^\circ\text{C}$)

Characteristics	Form	Symbol	Test Condition	Min	Typ.	Max	Unit
Trigger LED current	1a	I_{FT}	$I_{ON} = 100 \text{ mA}$	—	1	3	mA
	1b	I_{FC}	$I_{OFF} = 10 \mu\text{A}$				
Return LED current	1a	I_{FC}	$I_{OFF} = 10 \mu\text{A}$	0.1	—	—	mA
	1b	I_{FT}	$I_{ON} = 100 \text{ mA}$				
On-state resistance (Note 2)	—	R_{ON}	$I_{ON} = 100 \text{ mA}, t < 1\text{s}$	—	30	35	Ω
			$I_{ON} = 100 \text{ mA}$				

Note 2: 1-form-A: $I_F = 5 \text{ mA}$, 1-form-B: $I_F = 0 \text{ mA}$

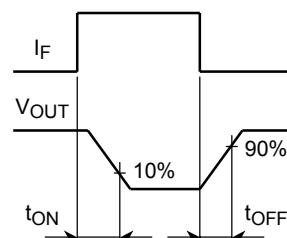
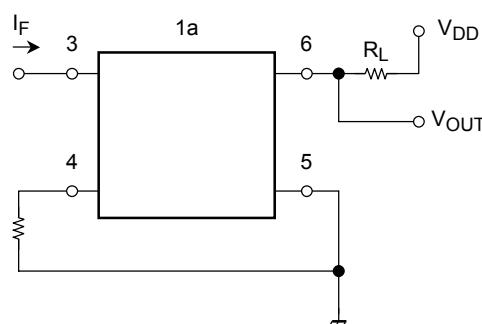
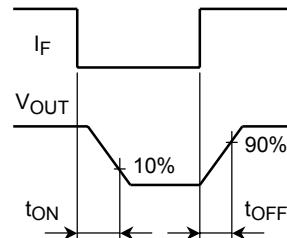
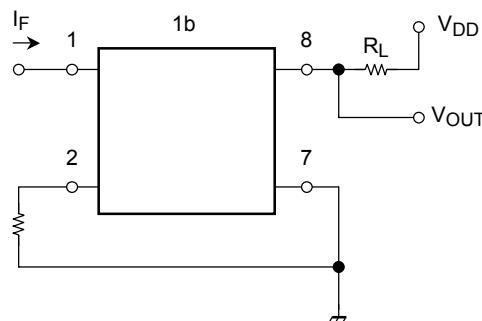
Isolation Characteristics ($T_a = 25^\circ\text{C}$)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Capacitance input to output	C_S	$V_S = 0, f = 1 \text{ MHz}$	—	0.8	—	pF
Isolation resistance	R_S	$V_S = 500 \text{ V}, \text{R.H.} \leq 60\%$	5×10^{10}	10^{14}	—	Ω
Isolation voltage	BV_S	AC, 1 min	2500	—	—	VRms
		AC, 1 s, in oil	—	5000	—	
		DC, 1 min, in oil	—	5000	—	Vdc

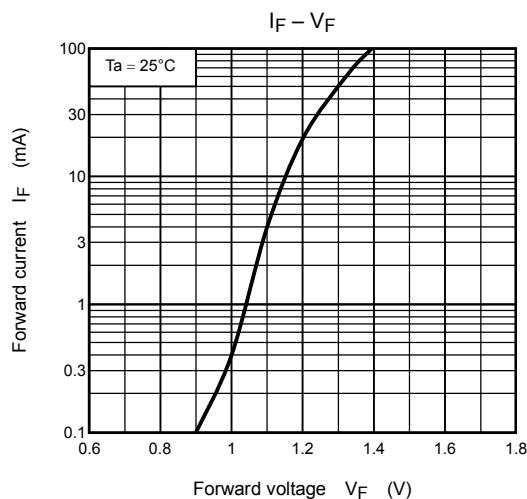
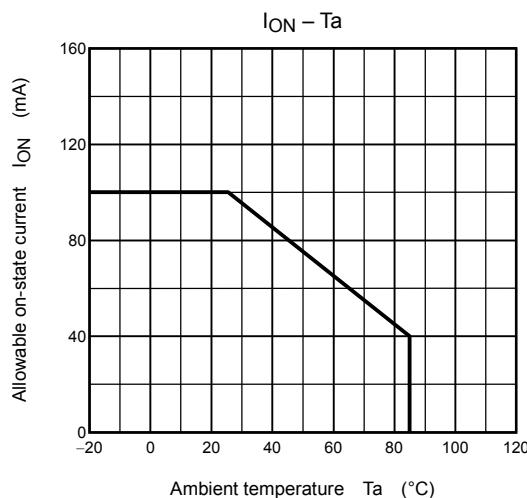
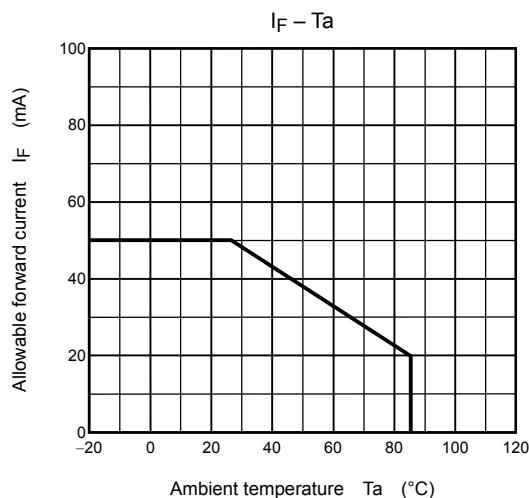
Switching Characteristics ($T_a = 25^\circ\text{C}$)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit		
1b	Turn-on time	t_{ON}	$R_L = 200 \Omega$ $V_{DD} = 20 \text{ V}, I_F = 5 \text{ mA}$	(Note 3)	—	0.25	1	ms
	Turn-off time	t_{OFF}			—	0.5	1	
1a	Turn-on time	t_{ON}	$R_L = 200 \Omega$ $V_{DD} = 20 \text{ V}, I_F = 5 \text{ mA}$	(Note 3)	—	0.3	1	ms
	Turn-off time	t_{OFF}			—	0.15	1	

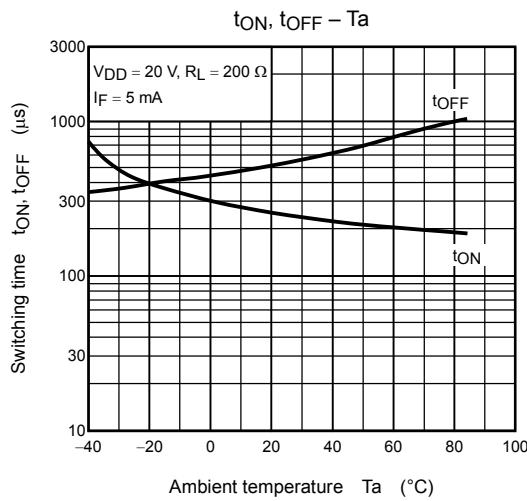
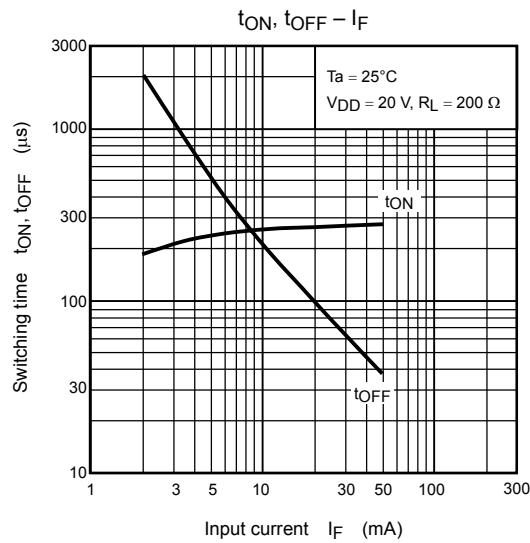
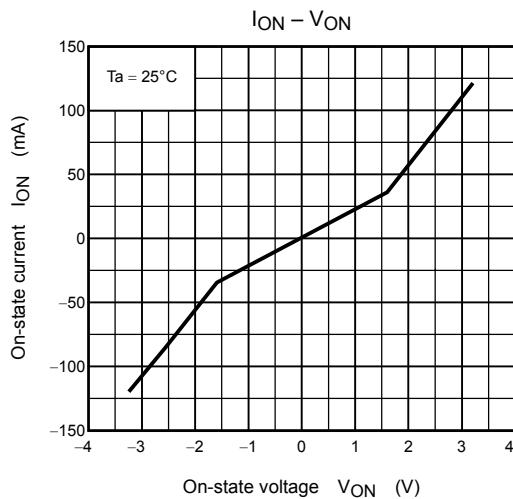
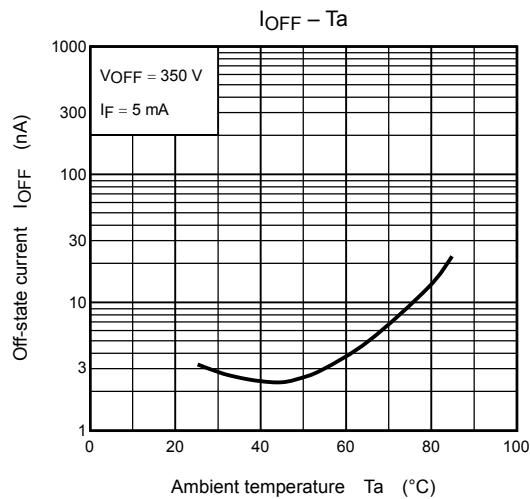
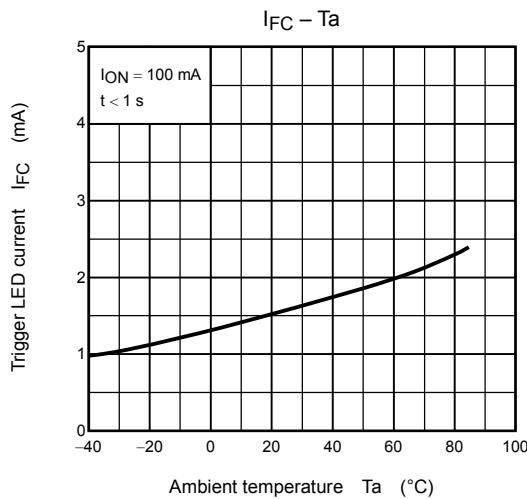
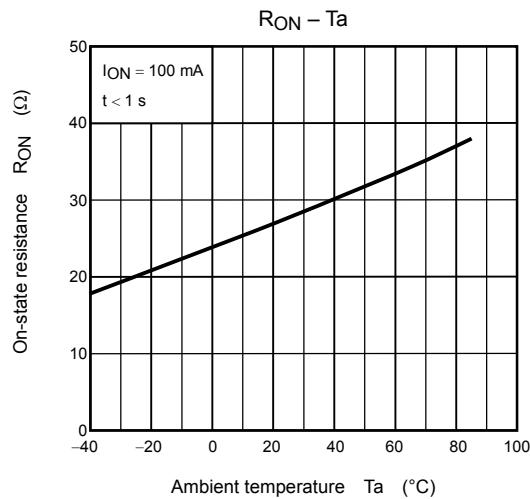
Note 3: Switching time test circuit



Characteristics curves for 1-form-A/B



Characteristics curves for 1-form-B



Characteristics curves for 1-form-A

